

New Product

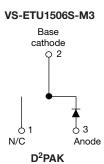
VS-ETU1506S-M3, VS-ETU1506-1-M3

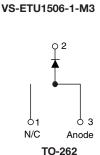
Vishay Semiconductors

Ultrafast Rectifier, 15 A FRED Pt[®]









PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	15 A
V _R	600 V
V _F at I _F	1.9 V
t _{rr} (typ.)	24 ns
T _J max.	175 °C
Diode variation	Single die

FEATURES

- Low forward voltage drop
- Ultrafast recovery time
- 175 °C operating junction temperature
- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition



FREE

Designed and qualified according to JEDEC-JESD47

DESCRIPTION/APPLICATIONS

State of the art, ultralow V_F , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 143 °C	15	•			
Non-repetitive peak surge current	I _{FSM}	T _C = 25 °C	160	A			
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C			

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
F 1 11	N	I _F = 15 A	-	1.35	1.9	V		
Forward voltage	V _F	I _F = 15 A, T _J = 150 °C	-	1.1	1.3			
		V _R = V _R rated	-	0.01	15			
Reverse leakage current	I _R	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	200	μA		
Junction capacitance	CT	V _R = 600 V	-	12	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH		

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Vishay Semiconductors Ultrafast Rectifier, 15 A FRED Pt®



DYNAMIC RECOVERY CH	IARACTER	RISTICS ($T_J = 25$	°C unless otherw	vise speci	fied)		
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/µs, V _R = 30 V	-	24	28	
Poverse receiver time	+	$I_{\rm F} = 15 \text{ A}, dI_{\rm F}/dt = 1000 \text{ A}$	100 A/µs, V _R = 30 V	-	36	47	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	ns
		T _J = 125 °C	I _F = 15 A dI _F /dt = 200 A/μs V _B = 390 V	-	87	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	5	-	A
Peak recovery current		T _J = 125 °C		-	9.0	-	A
	Q _{rr}	T _J = 25 °C		-	107	-	nC
Reverse recovery charge		T _J = 125 °C		-	430	-	ne
Reverse recovery time	t _{rr}		I _F = 15 A	-	53	-	ns
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 800 A/µs	-	25	-	А
Reverse recovery charge	Q _{rr}		V _R = 390 V	-	730	-	n

THERMAL - MECHANIC	THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C			
Thermal resistance, junction to case	R _{thJC}		-	1.3	1.51	°C/W			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-				
Waight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)			
Marking daying		Case style D ² PAK modified	ETU1506S						
Marking device		Case style TO-262	ETU1506-1						

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New Product

VS-ETU1506S-M3, VS-ETU1506-1-M3

Ultrafast Rectifier, 15 A FRED Pt[®] Vishay Semiconductors

1000 175 °C 100 100 Reverse Current - I_R (µA) 150 °C 10 125 °C 1 100 °C 75 °C 0.1 50 T_{.1} = 175 °C C 0.01 0.001 25 °C Instantaneous Forward Current I_F (A) 0.0001 0 100 200 400 500 600 300 Reverse Voltage - V_R (V) Fig. 2 - Typical Values of Reverse Current vs. 10 Reverse Voltage 1000 T_J = 150 °C Junction Capacitance-C_T (pF) 100 = 25 °C 10 1.0 1.5 2.0 2.5 1 0.5 100 200 600 0 300 400 500 Forward Voltage Drop - V_{FM} (V) Reverse Voltage-V_R (V) Fig. 1 - Typical Forward Voltage Drop Characteristics Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

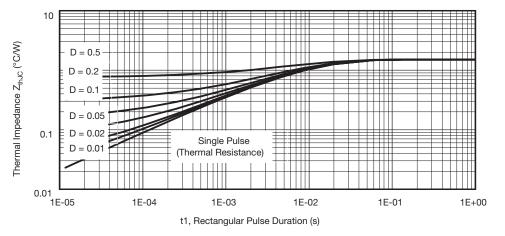


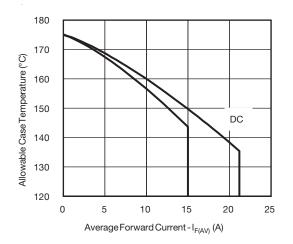
Fig. 4 - Max. Thermal Impedance $\mathsf{Z}_{\mathsf{thJC}}$ Characteristics

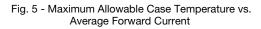
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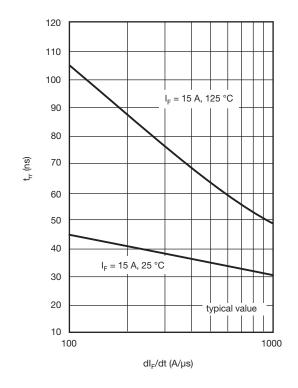


Fig. 7 - Typical Reverse Recovery Time vs. $dI_{\mbox{\scriptsize F}}/dt$

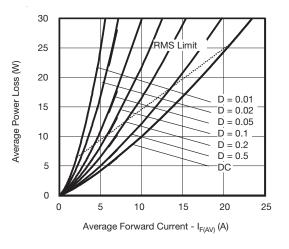


Fig. 6 - Forward Power Loss Characteristics

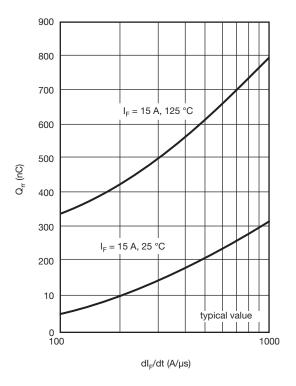


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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Ultrafast Rectifier, 15 A FRED Pt® Vishay Semiconductors

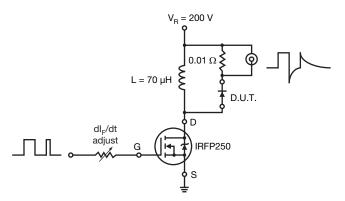


Fig. 9 - Reverse Recovery Parameter Test Circuit

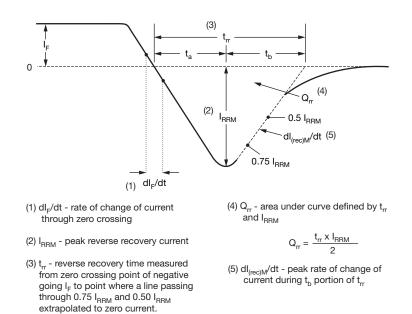


Fig. 10 - Reverse Recovery Waveform and Definitions

Vishay Semiconductors Ultrafast Rectifier, 15 A FRED Pt®



ORDERING INFORMATION TABLE

Device code	VS-	Е	т	U	15	06	S	TRL	-M3
		2	3	4	5	6	7	8	9
	1 -	- Visl	nay Sem	niconduo	ctors pro	oduct			
	2 -		uit conf Single	iguratior	ו				
	3 -		TO-220						
	4 -	• U =	Ultrafas	st recove	ery time				
	5 -	- Cur	rent coc	le (15 =	15 A)				
	6 -	· Vol	age coo	de (06 =	600 V)				
	7 -	• S	= D ² PA	K					
	-	• -1	= TO-2	62					
	8 -	• No	one = Ti	ube (50	pieces)				
	-	• TF	RL = Tap	pe and r	eel (left	oriente	d, for D ²	² PAK p	ackage
	-	• TF	RR = Ta	pe and i	eel (rigl	nt orient	ted, for	D ² PAK	packag
	9 -	M3	= Halo	gen-free	, RoHS	complia	ant, and	l termin	ations I

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-ETU1506S-M3	50	1000	Antistatic plastic tube					
VS-ETU1506-1-M3	50	1000	Antistatic plastic tube					
VS-ETU1506STRR-M3	800	800	13" diameter reel					
VS-ETU1506STRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS							
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046					
	TO-262AA	www.vishay.com/doc?95419					
Dort moreling information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information	TO-263AB (D ² PAK)	www.vishay.com/doc?95032					

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Outline Dimensions

Vishay Semiconductors

D²PAK



Conforms to JEDEC outline D²PAK (SMD-220) в Pad layout (2)(3)A 11.00 MIN.-(E) F (0.43)ŧ (3) L1 4 (|(0.38)^{MIN.} (D1) (3) Detail A D 17.90 (0.70) Н 15.00 (0.625) (2) З 0.15)^{0.01} Ľ L2 Ĥ ţ В В 2.32 MIN. (0.08) 2.64 (0.103) 2.41 (0.096) (3)Ċ 2 x b2 С View A - A 2 x h // ± 0.004 M B ⊕ 0.010 M A M B Base Plating (4) Metal 2 x e Н b1, b3 Gauge plane c1 (4) (c) В 0° to 8° ŧ. Seating Lead assignments plane L3 A1 Lead tip (b, b2) Diodes Section B - B and C - C 1. - Anode (two die)/open (one die) Scale: None 2., 4. - Cathode Detail "A" 3. - Anode

Rotated 90 °CW Scale: 8:1

SYMBOL	MILLIMETERS		INCHES		ES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Document Number: 95046 For technical questions within your region, please contact one of the following: Revision: 31-Mar-11 DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

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DIMENSIONS in millimeters and inches

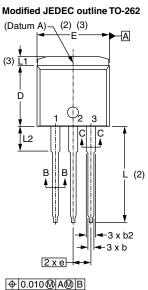


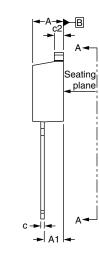
Outline Dimensions

Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches

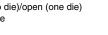


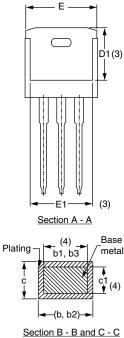


Lead assignments



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

SYMBOL	MILLIM	ETERS	INC	NOTEO	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10	0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

Revision: 04-Oct-10

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

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